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Transition metal chalcogenides as emerging triboelectric materials for high-performance energy harvesting devices

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The search for efficient, stable, and positive triboelectric materials is urgently needed to advance triboelectric nanogenerator (TENG) technology. Addressing this gap not only enhances device performance but also supports broader sustainability objectives, aligning with SDG-driven efforts toward clean energy, innovation, and responsible material use. While progress has been made with many negative triboelectric materials, the development of their positive counterparts remains limited. Therefore, bridging this gap is essential for achieving higher efficiency TENGs. In the present work, we propose transition metal chalcogenides (TMCs), specifically vanadium tetrasulfide (VS₄), as a new tribopositive material for the first time. The positive triboelectric nature of VS₄ is experimentally verified with simple electrostatic interaction tests, surface potential values and TENG-based tests. The VS₄-based TENG achieves an open-circuit voltage of ~1.52 kV, a short-circuit current of ~180 μA, a transferred charge of ~200 nC, and a power density of 14.45 W m⁻² under biomechanical hand-tapping force. The obtained performance is the highest among the sulphur-TMC-based TENGs reported to date. This high-performance TENG device was capable of powering a series-connected array of 720 light-emitting diodes (LEDs) and 6 LED bulbs. The present findings establish VS₄ as a new positive material for the development of triboelectric energy harvesting and self-powered systems.

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1. Introduction

The rapid advancement of self-powered systems has increased the need for efficient energy-harvesting technologies that convert ambient mechanical energy into electrical energy.¹ Since its first demonstration in 2012, the triboelectric nanogenerator (TENG) has emerged as a highly versatile and scalable energy conversion device through the synergistic effects of contact electrification and electrostatic induction.^{2–4} TENGs have demonstrated remarkable capability to harvest low-frequency mechanical energy from human motion, vibrations, wind, and water waves, making them promising candidates for applications in wearable electronics, autonomous sensors, and the Internet of Things (IoT).^{5–9} The overall performance of a TENG is predominantly determined by the triboelectric charge density generated during contact-separation, which strongly depends on the properties of the triboelectric materials, including their surface chemistry and

roughness, effective contact area, electronic structure, dielectric constant, and ability to sustain charge trapping.^{10–12} To achieve this goal, researchers across the globe have explored a wide range of organic materials, for example, polytetrafluoroethylene (PTFE), silicone elastomers, polyethylene terephthalate (PET), and Kapton, as well as inorganic materials including oxides, nitrides, 2D materials, metal organic frameworks (MOFs), MXenes, waste materials and carbon-based nanomaterials, along with their hybrid composites, to optimize triboelectric performance.^{1,13–19}

Among emerging materials, transition metal chalcogenides (TMCs) have attracted attention due to their unique combination of semiconducting behavior, high mechanical flexibility, and tuneable surface properties.^{17,20,21} In recent years, several TMCs, such as MoS₂, WS₂, MoSe₂, and WSe₂, have been successfully integrated into TENG architectures to enhance triboelectric performance and stability.^{22–26} Moreover, surface engineering of TMCs and the development of TMC-polymer composites have proven effective in enhancing charge transfer, sustaining surface charge retention, and improving the output stability of triboelectric devices. For example, surface functionalization of MoS₂ with aromatic carboxylic acids alters its work function and electron affinity, leading to improved triboelectric performance and higher output power in vertical contact-mode TENGs,²⁵ while WS₂-based TENGs achieve higher

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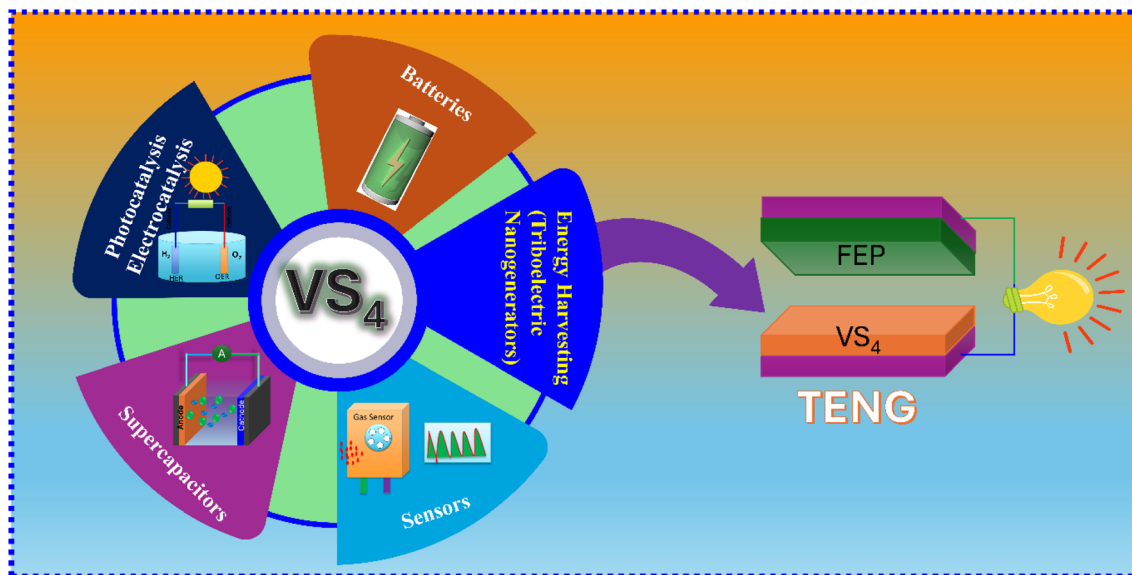


Fig. 1 Overview of VS_4 material applications in different fields with a proposed new energy harvesting application.

output voltage through thiol-ligand functionalization, which modulates surface electron affinity.²⁷ Bar-printed MoS_2 @PVDF hybrid nanocomposite films exhibit enhanced TENG performance, reaching approximately 200 V and 11.8 μA .²⁸ The incorporation of MoS_2 and post annealing promotes β -phase formation and induces polarity in PVDF, improving charge storage. These wearable TENGs demonstrate excellent long-term stability and can power mobile devices and other low-power electronics. Furthermore, newly explored transition-metal carbochalcogenides (TMCCs), such as $\text{Nb}_2\text{S}_2\text{C}$ and $\text{Ta}_2\text{S}_2\text{C}$, exhibit high power densities when incorporated into PDMS, highlighting the potential of layered chalcogenides for flexible triboelectric applications.²⁹

Vanadium tetrasulfide (VS_4), a quasi-one-dimensional (1D) chain-like chalcogenide, has attracted increasing research interest owing to its electrochemical activity, layered structure, and high intrinsic electrical conductivity.³⁰ Structurally, VS_4 consists of linear chains of V^{4+} ions coordinated to disulfide (S_2^{2-}) units. These atomic chains are held together by weak van der Waals interactions, resulting in a loosely stacked crystal framework.³¹ These distinctive features have enabled VS_4 to be explored in a variety of electrochemical and energy conversion applications, including batteries,^{32,33} supercapacitors,³⁴ photocatalytic systems,³⁵ gas sensors,³⁶ and electrocatalytic hydrogen evolution reaction (HER).³⁷ The material's narrow bandgap, high charge carrier mobility, and chemical stability make it a promising multifunctional candidate for next-generation energy devices. Despite extensive research on its electrochemical and catalytic properties, VS_4 has not yet been explored for TENG applications. Fig. 1 illustrates various existing applications of VS_4 , along with the proposed application of energy harvesting using TENG technology. This absence of study presents a significant research opportunity, as the material's semiconducting nature and electrical conductivity may substantially influence charge transport and retention mechanisms in TENG operation. To the best of the authors'

knowledge, this is the first report on VS_4 -based TENGs. Furthermore, this work directly contributes to SDG 7 (Clean Energy), SDG 9 (Industry & Innovation), and SDG 12 (Sustainable Production) by enabling a sustainable, battery-free, and efficient mechanical energy-harvesting technology.

In this work, we incorporated VS_4 -coated adhesive conductive carbon tape attached to an aluminum (Al) substrate as a triboelectric layer, paired with different counter triboelectric layers in a vertical contact-mode device architecture for energy harvesting. The triboelectric nature of VS_4 is experimentally validated using different methods. The resulting device, when paired with fluorinated ethylene propylene (FEP), demonstrated an open-circuit voltage of ~ 1.52 kV, a short-circuit output current density of ~ 180 μA , and a power density of 14.45 W m^{-2} . Finally, the VS_4 -FEP TENG was utilised to power a series-connected array of 720 LEDs and to generate sparks for applications such as microplasma generation, air ionisation, and electrostatic sterilisation. The future potential of VS_4 in triboelectric nanogenerators can be further explored by incorporating it into polymer matrices to improve device performance, stability, and durability.

2. Experimental

2.1 Materials

The precursor chemicals required for the synthesis of VS_4 , such as ammonium metavanadate (NH_4VO_3), thioacetamide ($\text{CH}_3\text{-CSNH}_2$), *N*-methyl-2-pyrrolidone (NMP), and ethanol (EtOH), were procured from Sisco Research Laboratories Pvt. Ltd (SRL).

2.2 Synthesis of VS_4

As shown in Fig. 2(a), VS_4 nanostructures were synthesised *via* a simple solvothermal method similar to the reported literature.^{36,38–40} NH_4VO_3 and CH_3CSNH_2 served as the vanadium and sulphur precursors, respectively. For stoichiometric synthesis,

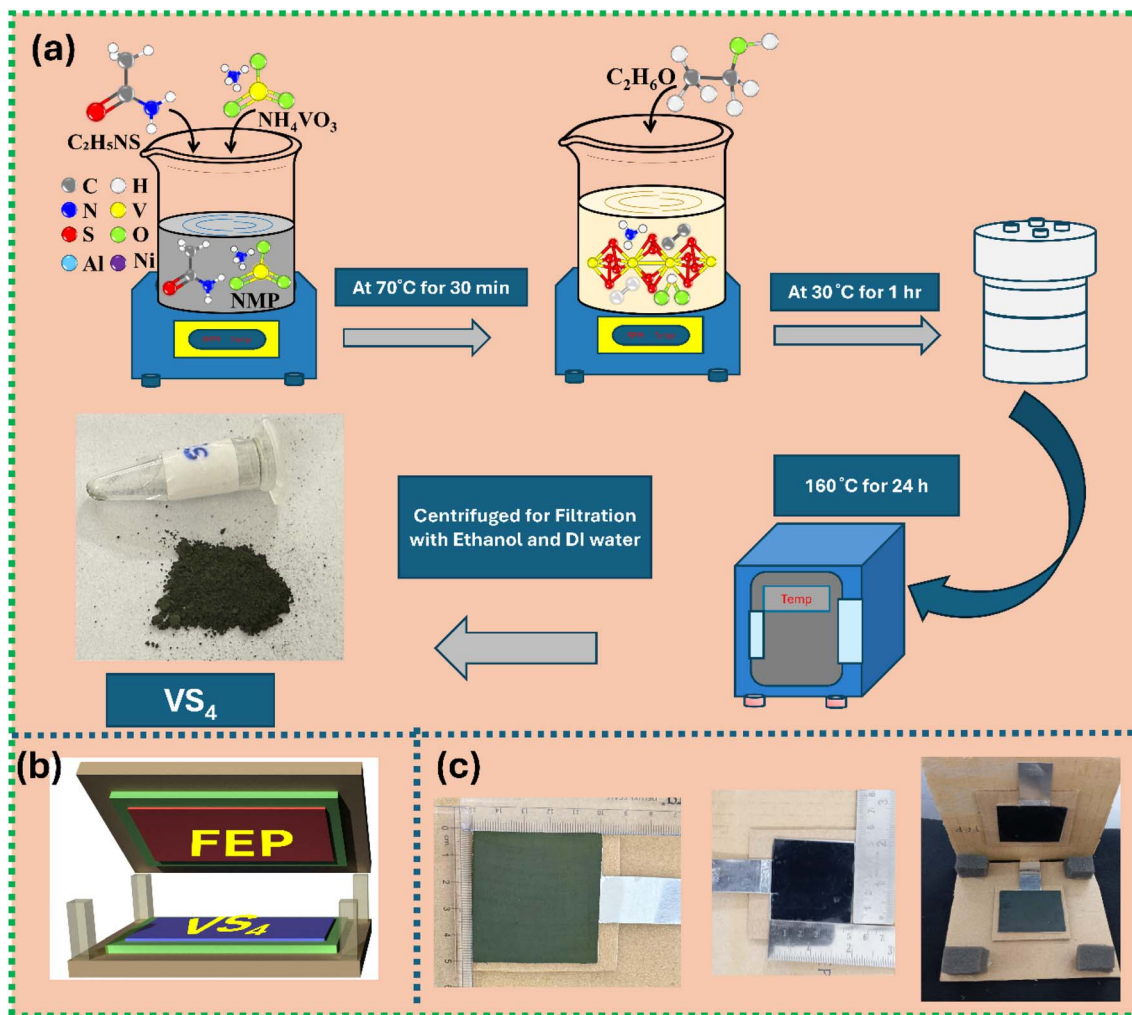


Fig. 2 (a) Synthesis procedure of VS_4 and the photograph of the obtained VS_4 powder, (b) schematic of the VS_4 -FEP TENG, and (c) photographs of the frictional layers VS_4 , FEP and the fabricated VS_4 -FEP TENG, respectively.

0.855 mmol of NH_4VO_3 and 4 mmol of CH_3CSNH_2 were dissolved in 20 mL of *N*-methyl-2-pyrrolidone (NMP). The mixture was magnetically stirred at 70 °C for 30 minutes to ensure complete dissolution and uniform mixing of the precursors. Then, 20 mL of ethanol was added dropwise under continuous stirring at 30 °C for 1 hour. The homogeneous solution was transferred into an 80 mL Teflon-lined stainless-steel autoclave and heated at 160 °C for 24 hours. After the reaction, the autoclave was left to cool naturally to room temperature. The dark green precipitate was collected by centrifugation at 8000 rpm, and then washed multiple times with deionised water and ethanol to eliminate residual ions or organic impurities. Finally, the product was vacuum-dried at 80 °C overnight to produce VS_4 powder. Fig. 2(a) also shows the photograph of the obtained powder, which appears dark in colour.^{41,42}

2.3 Formation mechanism of VS_4 nanostructures

During the solvothermal process, thioacetamide (CH_3CSNH_2) plays a dual role as both a sulfur source and a mild reducing agent. At elevated temperature, thioacetamide undergoes hydrolysis to release hydrogen sulfide (H_2S), which subsequently provides S^{2-}

ions in the reaction medium. Simultaneously, NH_4VO_3 partially dissociates to yield VO_3^- and NH_4^+ ions in NMP-ethanol solution. The S^{2-} ions generated from thioacetamide gradually react with V^{5+} species from NH_4VO_3 , resulting in the stepwise reduction of vanadium and the formation of intermediate vanadium oxysulfide (V-O-S) complexes. With prolonged reaction at 160 °C, these intermediates are further sulfurized to form crystalline VS_4 through anion exchange and self-assembly processes:

NMP offers strong coordination to vanadium species, preventing premature nucleation, while ethanol promotes controlled reduction and diffusion of sulfur species. The gradual nucleation and anisotropic growth under solvothermal conditions lead to the sheet/flake-like morphology. This hierarchical structure provides a large surface area and abundant active sites, which are advantageous for charge transfer and energy-harvesting applications.

2.4 Materials characterization

The obtained VS_4 powder was affixed to conductive carbon tape for morphological and compositional studies using field-

emission scanning electron microscopy (FESEM) (JEOL JSM-IT800). Phase identification and crystallinity were assessed by powder X-ray diffraction (PXRD) measurements, using an Anton Paar diffractometer (model: XRDYNAMIC500).

2.5 Fabrication and electrical characterization of the VS₄-TENG

A schematic of the fabricated TENG device is shown in Fig. 2(b) in vertical contact-separation mode. Initially, conductive carbon tape was affixed onto a $5 \times 5 \text{ cm}^2$ Al substrate. On top of this tape, the synthesised VS₄ powder was uniformly coated using a soft brush. Any loosely bound powder particles were subsequently removed using air gun. The Al substrate coated with VS₄ served as the triboelectric positive layer and was mounted onto a cardboard sheet support to minimize undesired triboelectric effects from handling. Similarly, another Al substrate of identical dimensions ($5 \times 5 \text{ cm}^2$) was covered with adhesive conductive carbon tape, upon which a fluorinated ethylene propylene (FEP) film was laminated to serve as the negative triboelectric layer. This FEP-mounted Al electrode was also attached to a separate cardboard sheet. To assemble the device, sponge spacers were positioned at the four corners of one of the support cards to maintain a uniform air gap ($\sim 1 \text{ cm}$) between the two frictional layers. These elastic spacers acted as restoring elements, enabling the layers to separate automatically after each contact during mechanical tapping. The photographs of the prepared frictional layers and the assembled device are shown in Fig. 2(c). A series of six TENG devices was fabricated by pairing the fixed VS₄ layer with different counter triboelectric materials to evaluate performance variations. The different counter triboelectric layers include polyethylene terephthalate (PET), poly methyl methacrylate (PMMA), Kapton, polytetrafluoroethylene (PTFE), silicone rubber and fluorinated ethylene propylene (FEP).

The electrical performance of the fabricated TENGs was tested under hand-tapping-induced biomechanical excitation at a frequency of approximately 4–5 Hz under ambient laboratory conditions. The open-circuit voltage (V_{oc}) and short-circuit current (I_{sc}) were recorded using a digital storage oscilloscope (DSO) and a low-noise current pre-amplifier (Stanford Research Systems, SR-570), respectively. The transferred charge was measured using an electrometer (Keithley 6514). The surface potential of the triboelectric layers was measured using a Trek 542A electrostatic voltmeter. The load-dependent output characteristics were determined using a decade resistance box, and long-term durability was assessed using an in-house-developed linear motor setup, which was operated for over ~ 8500 continuous contact-separation cycles and hand-tapped for 1500 cycles.

3. Results and discussion

3.1 Characterization of VS₄

The crystal structure of the synthesised VS₄ powder was examined using X-ray diffraction (XRD) analysis, and the XRD pattern is shown in Fig. 3(a). The major diffraction peaks located at 2θ

values around 15.7° and 16.8° were indexed to the (110) and (020) planes of the monoclinic phase of VS₄ (JCPDS No. 072-1294).^{38,43,44} The sharp, well-defined peaks confirm the high crystallinity of the prepared VS₄ powder. The absence of impurity peaks related to vanadium oxides or sulfides (*e.g.*, V₂O₅ and VS₂) indicates the phase purity of the obtained VS₄. The surface morphology of the VS₄ powder was investigated by FESEM and is presented in Fig. 3(b) and (c) at low and high magnifications. The micrographs reveal a uniform sheet-like or flower-like architecture, consistent with the reported literature.⁴⁵ Such a hierarchical structure provides a high surface area and abundant active sites, which are advantageous for triboelectric and electrochemical energy harvesting applications. Energy-dispersive X-ray spectroscopy (EDX) analysis shown in Fig. 3(d) confirms the presence of vanadium (V) and sulfur (S) as the only constituent elements without any other impurities other than small oxygen content due to oxidation.

3.2 Energy harvesting evaluation of the VS₄-TENG

The fabricated VS₄-based TENGs were evaluated for their biomechanical energy harvesting performance. The V_{oc} and I_{sc} responses of the TENG devices are presented in Fig. 4(a) and (b). Both V_{oc} and I_{sc} of VS₄-based TENGs with different opposite frictional layers exhibit a similar trend, showing the lowest output with positive triboelectric layers (PET and PMMA) and the highest output with negative triboelectric layers (silicone rubber and FEP). This observation clearly indicates that VS₄ acts as a triboelectrically positive material, and hence, can be placed on the positive side of the triboelectric series. The maximum V_{oc} and I_{sc} of $\sim 1524 \text{ V}$ and $\sim 180 \mu\text{A}$ were obtained for the VS₄-FEP TENG, which was subsequently used for further studies. Fig. 4(c) and (d) shows the switching polarity test responses of the TENG, and it confirms the electrical output generated by the TENG device and not from any noise or artefacts.^{46,47} Furthermore, the transferred charge during TENG operation is presented in Fig. 4(e).

The observed triboelectric positivity of VS₄ is proposed to originate from its metallic-semiconducting character combined with sulfur-rich surface termination, which leads to an electron-deficient surface and a strong tendency to donate electrons upon contact with highly electronegative materials such as FEP. The tribo-positive nature of VS₄ primarily arises from the electron-deficient V⁴⁺ centers coordinated by sulfur ligands. Although no permanent redox reaction occurs during contact electrification, the intrinsic electronic structure of vanadium, reflecting its thermodynamic preference toward higher oxidation states, results in reduced surface electron density and facilitates surface electron transfer. Furthermore, the disulfide (S₂²⁻) ligands surrounding the vanadium centers exert a strong electron-withdrawing effect, creating a hole-rich surface. This synergistic electronic environment enhances electron donation from VS₄ to tribo-negative polymers such as FEP, enabling efficient charge transfer and improved output performance in TENGs.

The triboelectric nature of the synthesised VS₄ powder was further verified through a simple electrostatic interaction

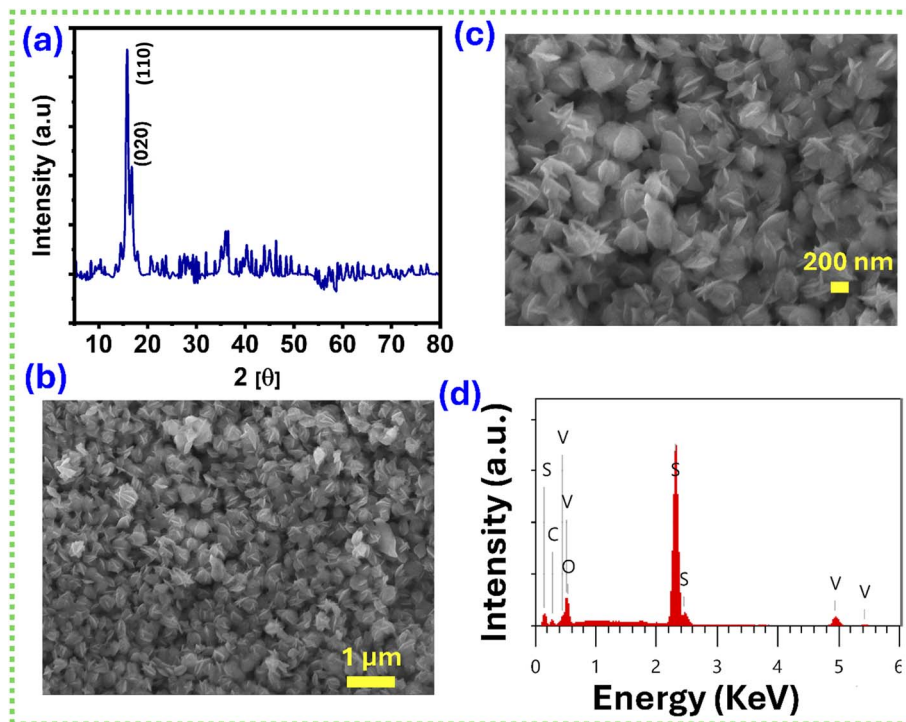


Fig. 3 (a) XRD pattern of VS_4 , (b) and (c) morphology of the VS_4 powder, and (d) EDX spectrum of the VS_4 powder.

experiment. The VS_4 powder was gently spread on a plain white sheet of paper, while a Teflon rod was separately rubbed against a silk cloth to induce negative surface charges. When the negatively charged Teflon rod was brought close to the VS_4 powder, the powder particles were observed to be strongly

attracted towards the Teflon surface. This clear electrostatic attraction confirms the positive triboelectric polarity of the VS_4 material. The corresponding photographs of the Teflon surface before and after interaction with VS_4 powder are presented in Fig. 4(f), and a real-time demonstration of the phenomenon is

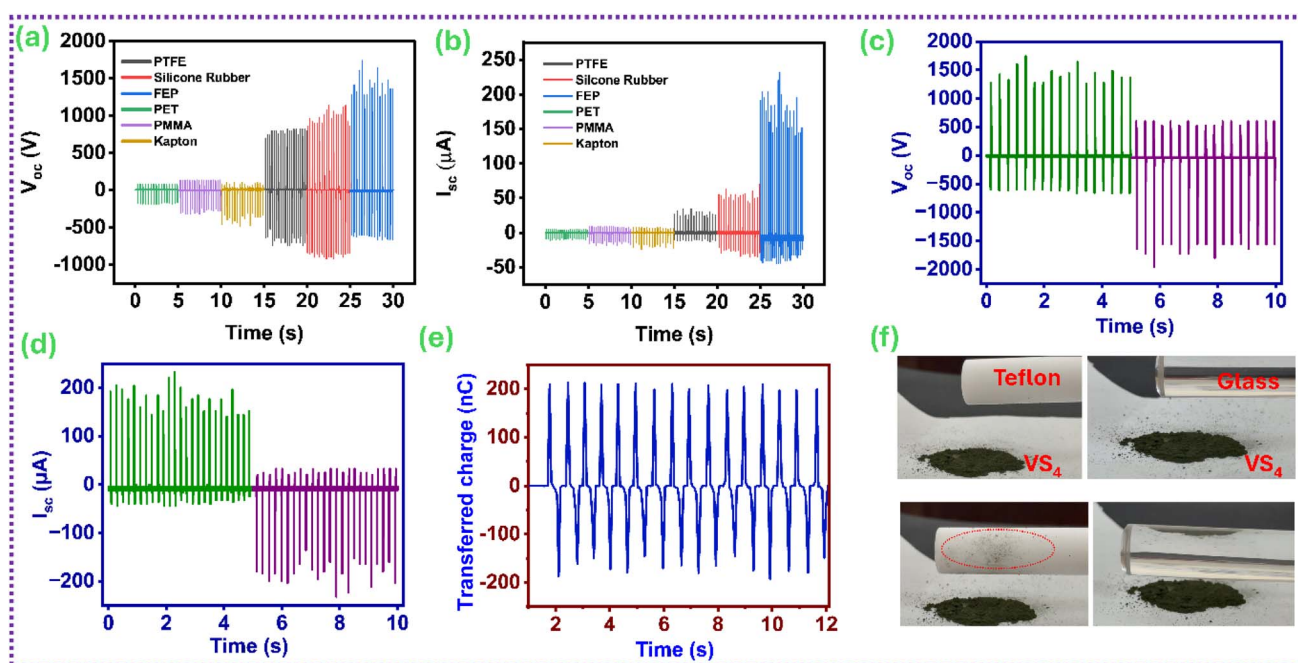


Fig. 4 Electrical output performance of VS_4 -based TENGs: (a) V_{OC} and (b) I_{sc} with different opposite layers showing positive triboelectric behaviour of VS_4 . (c and d) Time-dependent V_{OC} and I_{sc} of the VS_4 -FEP TENG in switching polarity mode, (e) transferred charge, (f) electrostatic attraction and repulsion of VS_4 powder with a Teflon rod and a Pyrex glass rod, respectively.

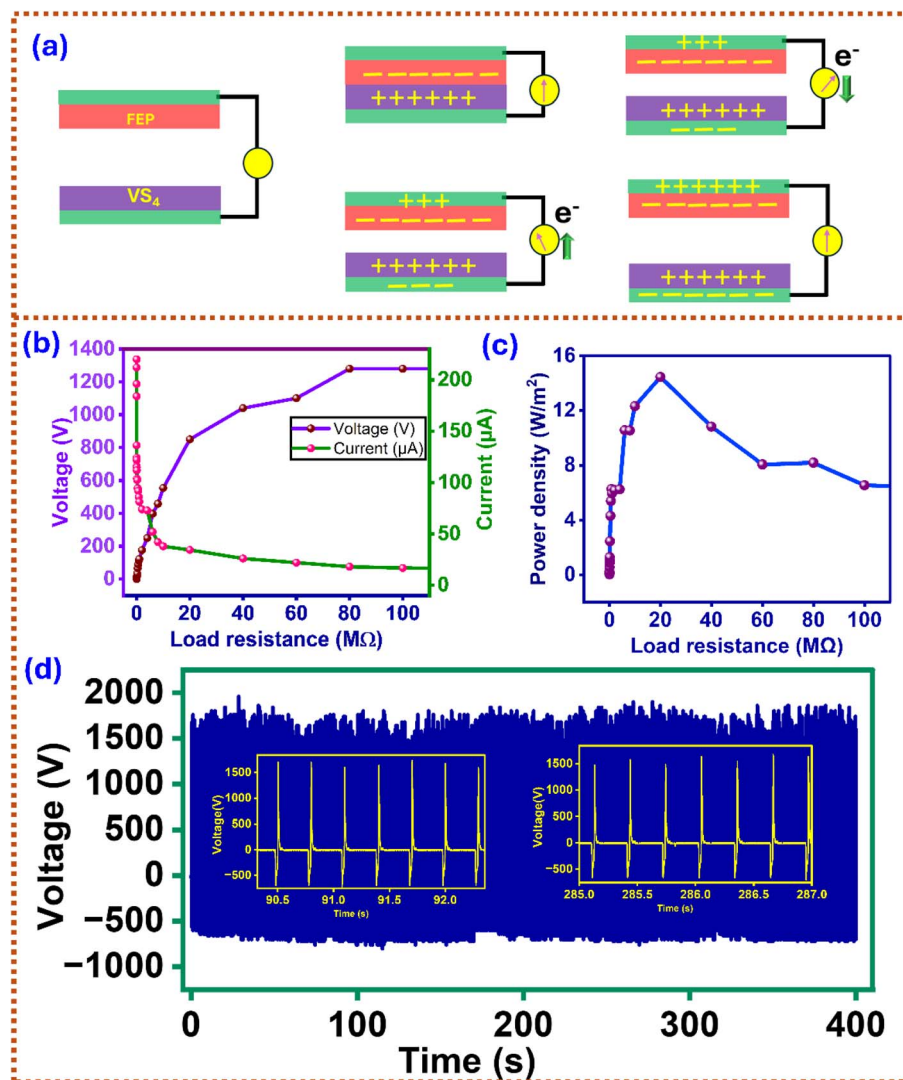


Fig. 5 (a) Working mechanism of the VS₄-FEP TENG, (b) voltage and current values of the VS₄ TENG with load resistance, (c) power density versus load resistance, and (d) long-term stability of the TENG over 1500 cycles (inset: magnified view of a few cycles).

provided in the SI, Video S1. In addition to this, we have also tested the electrostatic interaction of VS₄ powder with a positively charged Pyrex glass rod and found no attraction of the VS₄ particles towards the glass rod, as shown in Fig. 4(f) (SI, Video S2). This experimental verification confirms the triboelectric positive nature of VS₄. Additionally, the surface potential of a VS₄ powder film was measured after repeated contact with a FEP layer. The VS₄ film exhibited a positive surface potential of +1.17 kV, offering independent verification of its tribo-positive behavior. The real-time photograph during the testing is presented in SI Fig. S1.

Based on this confirmation of the VS₄ triboelectric positive nature, the working mechanism of the VS₄-FEP TENG is illustrated in Fig. 5(a). In the initial state (without external mechanical force), both triboelectric layers remain separated, and no charge transfer occurs across the interface, resulting in zero potential difference and no current flow in the external circuit. When a mechanical force is applied, the VS₄ and FEP

layers come into intimate contact, leading to charge transfer driven by their difference in electron affinities. Owing to its lower electronegativity, VS₄ tends to lose electrons, becoming positively charged, while the FEP layer gains electrons, acquiring a net negative charge. Upon release of the applied hand-tapping force, the frictional layers separate, producing a potential difference between the electrodes that drives current through the external circuit until electrostatic equilibrium is reached. Re-application of mechanical force leads to reverse current flow in the external circuit, generating alternating current (AC) pulses with each contact-separation cycle. Hence, repetitive mechanical stimuli result in continuous AC output in the external circuit.

The load characteristics of the VS₄-based TENG were studied by varying the external load resistance from 1 kΩ to 100 MΩ, and the results are presented in Fig. 5(b). With increasing load resistance, the output voltage increased monotonically and eventually saturated at higher values, whereas the current

Table 1 Review of TENG device performances based on sulphur chalcogen-based TMC materials

Sl. no.	TMC material	Opposite frictional layer	V_{oc}	I_{sc}	Power density	Ref.
1	PVC/MoS ₂ composite	PA	398 V	40 μ A	1.025 W m ⁻²	49
2	MoS ₂ /PAN fibers	Nylon	245.3 V	5.12 μ A	1.75 W m ⁻²	50
	MoS ₂ /PDMS		410 V	42 μ A	4.52 W m ⁻²	51
	MoS ₂ -4,4'-(oxybis)benzoic acid	Kapton	30 V	0.3 μ A	399 mW m ⁻²	25
3	WS ₂	PMMA	520 V	68 mA m ⁻²	0.6 W m ⁻²	23
4	WS ₂	ITO	30 V	0.3 μ A	40 mW m ⁻²	52
5	Cds-PDMS	Cu	236 V	17.4 μ A	4 W m ⁻²	53
6	ZnS	PDMS	8 V	7.12 μ A	0.43 μ W m ⁻²	54
7	VS ₄	FEP	1.52 kV	180 μ A	14.45 W m ⁻²	Present work

decreased correspondingly due to ohmic losses. This behavior of current and voltage with load resistance is consistent with the typical load characteristics of TENGs reported in the literature.⁴⁸ The instantaneous power density ($P = V^2/R_L A$) is calculated from the voltage-load resistance data and is shown in Fig. 5(c). A maximum power density of $\approx 14.45 \text{ W m}^{-2}$ under an optimal load-matching condition of 20 M Ω is observed. A comparative analysis of the VS₄-based TENG performance with previously reported TMC-based TENGs is presented in Table 1, demonstrating that the present device exhibits superior output performance in terms of voltage, current and power density.

Furthermore, the long-term operational stability of the VS₄-TENG was evaluated over 1500 consecutive hand-tapping cycles and 8500 machine-tapping cycles. Initially, the TENG was tested using an in-house-developed linear motor, with tapping for 8500 cycles; the results are shown in the SI, Fig. S2. Following the machine tapping test, the same TENG device underwent an additional 1500 hand-tapping cycles, and the results are shown in Fig. 5(d).

The device maintained remarkably stable voltage output throughout the entire test duration, indicating excellent mechanical durability and interfacial robustness of the

triboelectric layers. The inset in Fig. 5(d) shows an enlarged view of several consecutive cycles, further confirming the device's reproducible and consistent performance over extended operation.

3.3 Application of the VS₄-TENG

To validate the practical energy-harvesting capability of the fabricated VS₄-based TENG, the generated electrical output was utilised to power a large array of 720 light-emitting diodes (LEDs) connected in series and mounted on multiple inter-connected breadboards. Upon a single hand tap or gentle press on the VS₄-TENG, the accumulated surface charge and induced potential difference produced a high-voltage pulse sufficient to momentarily drive all LEDs simultaneously, resulting in bright and instantaneous illumination, as shown in Fig. 6(a). The real-time video demonstration of powering LEDs is presented in SI, Video S3. Similarly, a fabricated TENG can power 6 LED bulbs for a momentarily with each tap, as shown in Fig. 6(b). The real-time video demonstration of powering LED lamps is presented in SI, Video S4. These clear and uniform lighting responses indicate the TENG's ability to deliver high instantaneous current and voltage peaks, converting low-frequency

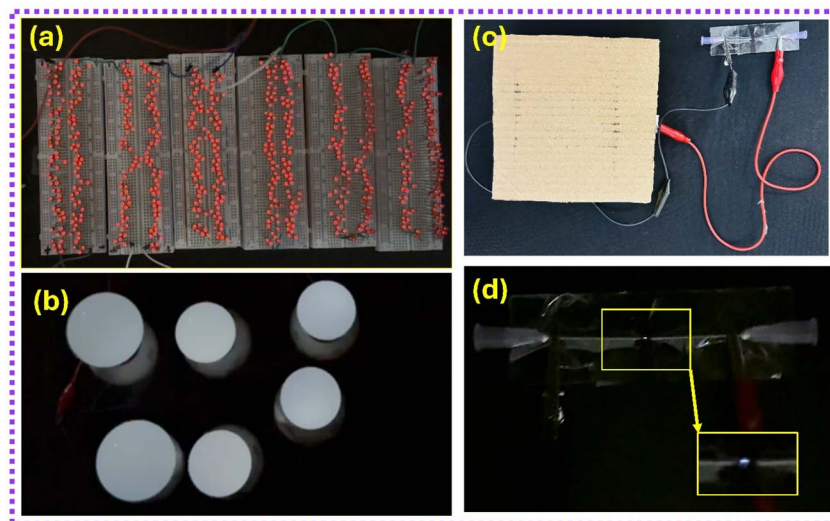


Fig. 6 (a) Photograph showing the instantaneous illumination of (a) 720 red LEDs, (b) LED lamps by the VS₄-FEP TENG upon a single hand tap, (c) experimental setup for electrical spark generation using the VS₄-FEP TENG, and (d) optical image showing a bright spark discharge between the needle tips (inset: magnified view).

biomechanical energy into usable electrical power without an external energy source.

Beyond energy-harvesting demonstrations, the VS₄-FEP based TENG was further evaluated for force-sensing applications by applying mechanical stimuli using different numbers of fingers (one to four). As shown in SI, Fig. S3, the output voltage increases systematically with the number of fingers: single-finger pressing produces lower voltage peaks, whereas multi-finger pressing yields progressively higher outputs. This behavior is attributed to enhanced interfacial charge generation arising from increased contact area and applied force between the friction layers. The clear, repeatable, and force-dependent electrical response confirms the high sensitivity of the VS₄-FEP TENG, highlighting its potential as a self-powered force sensor for tactile sensing,^{55,56} wearable electronics,⁵⁷ and human-machine interface applications.⁵⁸

To further demonstrate the high-voltage output capability of the fabricated VS₄-FEP based TENG, a simple spark generation experiment was carried out. The experimental step up is shown in Fig. 6(c). The output terminals of the TENG were connected to two stainless-steel needle electrodes, which were fixed on an insulating acrylic base with an adjustable air gap of approximately 1–2 mm. Upon hand tapping the TENG, the accumulated triboelectric charges on the VS₄ and FEP surfaces induced a high potential difference across the electrodes, exceeding the air breakdown voltage. As a result, a visible spark discharge was observed between the needle tips (Fig. 6(d), bottom, inset), confirming that the generated V_{oc} of the VS₄-FEP based TENG reached the kilovolt level (SI, Video S5). The observed spark confirms that the VS₄-FEP TENG can serve as a self-powered high-voltage source suitable for applications such as micro-plasma generation, air ionisation, and electrostatic sterilisation.

4. Conclusions

In summary, we have demonstrated the use of VS₄ as a new triboelectric-positive material for TENGs in efficient energy harvesting applications. The synthesised VS₄ exhibited excellent crystallinity and sheet-like morphology, enabling effective charge transfer when paired with negative triboelectric materials such as FEP. The fabricated VS₄-FEP based TENG delivered a high open-circuit voltage of ~1.52 kV, a short-circuit current of around 180 μ A, and a power density of 14.45 W m⁻², confirming its strong capability to harvest biomechanical energy. Furthermore, the device was able to light up 720 LEDs, 6 LED bulbs and generate electrical sparks, highlighting its potential as a self-powered high-voltage source for advanced applications such as micro-plasma generation, air ionisation, and electrostatic sterilisation. This study establishes VS₄ as a promising triboelectric-positive material and suggests that other transition metal chalcogenides may also merit exploration for high-performance triboelectric nanogenerators.

Author contributions

M. Gopinath: data curation: lead; formal analysis: lead; investigation: lead; methodology: lead; writing – original draft:

supporting. Rajesh Katru: data curation: supporting; formal analysis: supporting; investigation: supporting; methodology: supporting; writing – original draft: supporting. Navaneeth Madathil: data curation: supporting; formal analysis: supporting; investigation: supporting; methodology: supporting; visualization: supporting. Pambarthi Raju: data curation: supporting; formal analysis: supporting; investigation: supporting; methodology: supporting. Uday Kumar Khanapuram: conceptualization: equal; data curation: supporting; formal analysis: supporting; methodology: supporting; project administration: supporting; resources: supporting; supervision: equal; writing – review & editing: equal. Ravinder Reddy Kisannagar: data curation: supporting; formal analysis: supporting; methodology: supporting; validation: supporting; visualization: supporting; writing – original draft: supporting; writing – review & editing: supporting. Inhwa Jung: data curation: supporting; formal analysis: supporting; methodology: supporting; validation: supporting; visualization: supporting; writing – review & editing: equal. Rakesh Kumar Rajaboina: conceptualization: lead; project administration: lead; resources: lead; supervision: lead; validation: lead; visualization: lead; writing – original draft: supporting; writing – review & editing: lead.

Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

Data availability

The data supporting this article have been included as part of the supplementary information (SI). Supplementary information is available. See DOI: <https://doi.org/10.1039/d5se01579k>.

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